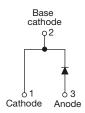


www.vishay.com

Vishay Semiconductors

High Performance Schottky Rectifier, 10 A



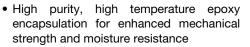


TO-220AC 2L

PRIMARY CHARACTERISTICS							
I _{F(AV)}	10 A						
V _R	35 V, 45 V						
V _F at I _F	0.57 V						
I _{RM} max.	15 mA at 125 °C						
T _J max.	150 °C						
E _{AS}	8 mJ						
Package	2L TO-220AC						
Circuit configuration	Single						

FEATURES

- 150 °C T_J operation
- High frequency operation
- · Low forward voltage drop





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES								
I _{F(AV)}	Rectangular waveform	10	^					
I _{FRM}	T _C = 135 °C	20	Α					
V _{RRM}		35/45	V					
I _{FSM}	t _p = 5 μs sine	1060	Α					
V _F	10 A _{pk} , T _J = 125 °C	0.57	V					
T _J	Range	-65 to +150	°C					

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-MBR1035-M3	VS-MBR1045-M3	UNITS					
Maximum DC reverse voltage	V_R	35	45	V					
Maximum working peak reverse voltage	V_{RWM}	33	43	V					

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
Maximum average forward current	I _{F(AV)}	T _C = 135 °C, rated V _R	T_C = 135 °C, rated V_R					
Peak repetitive forward current	I _{FRM}	Rated V _R , square wave, 20	Rated V _R , square wave, 20 kHz, T _C = 135 °C					
Non-repetitive peak surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{BRM} applied		А			
		Surge applied at rated load single phase, 60 Hz	150					
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2 \text{A}, L = 4$	8	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to Frequency limited by T _J ma	2	Α				

VS-MBR1035-M3, VS-MBR1045-M3

Vishay Semiconductors

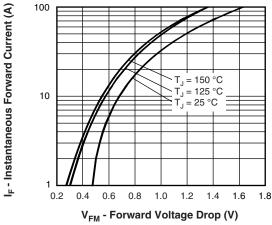
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
		20 A	T _J = 25 °C	0.84				
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	T. = 125 °C	0.57	V			
		20 A	1	0.72				
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.1	mΛ			
Maximum instantaneous reverse current		T _J = 125 °C	hated DC voltage	15	mA			
Threshold voltage	V _{F(TO)}	T T mayimum		0.354	V			
Forward slope resistance	r _t	ıj = ıj maxımum	$T_J = T_J$ maximum		mΩ			
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	600	pF				
Typical series inductance	L _S	Measured from top of term	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

 $^{(1)}\,$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction temperature range	TJ	T _J		°C				
Maximum storage temperature range	T _{Stg}		-65 to +175					
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.0	°C/W				
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased		C/VV				
Approximate weight			2	g				
Approximate weight			0.07	oz.				
Mounting torque minimum			6 (5)	kgf · cm				
maximum			12 (10)	(lbf · in)				
Marking dovice		Casa atula 21 TO 220AC	MBR1035					
Marking device		Case style 2L TO-220AC		1045				

Vishay Semiconductors





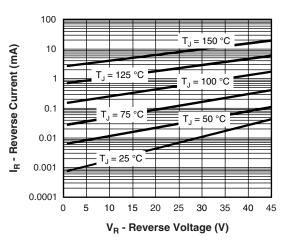


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

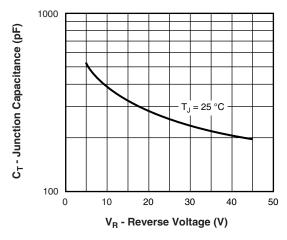


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

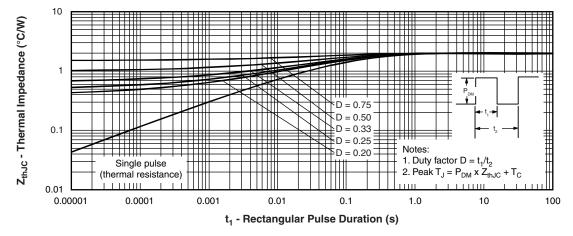


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



Allowable Case Temperature (°C)

www.vishay.com

Vishay Semiconductors

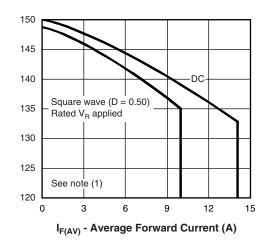


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

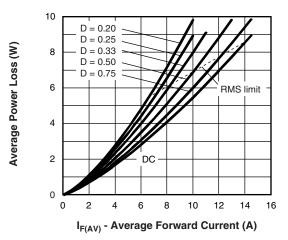


Fig. 6 - Forward Power Loss Characteristics

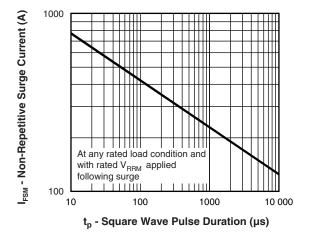


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

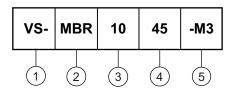
 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = rated V_R

VS-MBR1035-M3, VS-MBR1045-M3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product

2 - Schottky MBR series

- Currrent rating (10 = 10 A)

Voltage ratings 35 = 35 V 45 = 45 V

5 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-MBR1035-M3	50	Antistatic plastic tubes						
VS-MBR1045-M3	50	Antistatic plastic tubes						

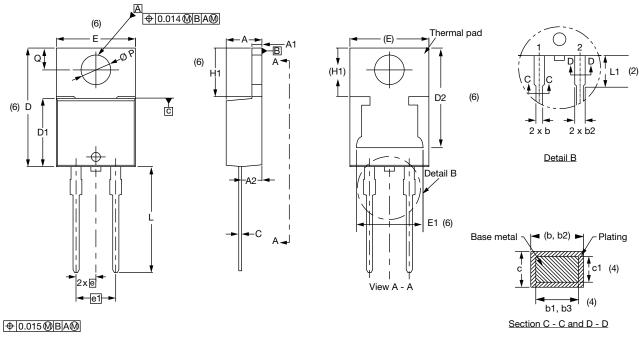
LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?96156							
Part marking information	www.vishay.com/doc?95391						
SPICE model	www.vishay.com/doc?95293						



Vishay Semiconductors

TO-220AC 2L

DIMENSIONS in millimeters and inches



Lead tip

Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIN	IETERS	INC	HES	NOTES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355							•	

Notes

- $^{(1)}$ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.